Influence of Geometry of Metallic Nanoparticles on Absorption of Thin-Film Organic Solar Cells: A Critical Examination

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ABSTRACT Well-engineered light trapping designs will significantly improve power conversion efficiency of thin-film organic solar cells. Recently, metallic nanoparticles (NPs) have been widely used to concentrate sunlight in the active layer of OSCs. To critically examine the influence of geometry of metallic NPs on absorption of OSCs, the parallel finite-element method is applied to simulate the near-field multiple scattering effects in plasmonic NPs incorporated OSCs. The geometry-varied NPs including nano-cone, nano-inverted-cone, nano-cylinder, and nano-cuboid are systematically investigated. Furthermore, the absorption enhancement from the dielectric silicon NPs and perfectly reflecting NPs are also comprehensively offered. Compared to the off-plasmon resonance case, the absorption enhancement factor is higher for on-plasmon resonance case. However, the absorption of organic active material near plasmon resonance weakly contributes to exciton generation. Moreover, the height-dependent Fabry-Perot mode plays a key role in the light trapping off the plasmon resonance. Additionally, the tapered structure of the silver nano-cone, which leads to the best absorption enhancement of 3 at the wavelength of 680 nm, since it can reduce unwanted reflection loss and achieve broadband plasmonic resonance simultaneously.

INDEX TERMS Plasmonic effect, organic solar cell, metallic nanoparticles, finite-element method.

I. INTRODUCTION Thin-film organic solar cells (OSCs) have a great potential to generate electrical energy as a renewable energy source [1], [2]. In recent years, the research of organic solar cells has made great progress, and the photoelectric conversion efficiency has been constantly improved. The material of active layer plays a key role in improving power conversion efficiency. P3HT:PCBM is a good candidate for active layer because of its low cost and environmental sustainability. However, compared with the conventional inorganic or perovskite solar cells, the PCE for OPV devices should be further improved. The conflict between the need of thick active layer to ensure sufficient photon absorption and maintaining thin film due to the relatively low carrier mobility and short exciton diffusion length of organic materials is one of the main obstacles for the efficiency enhancement. More specifically, the absorption of OSCs have been enhanced [4] by metallic nanoparticles (NPs), which excite localized plasmonic resonances (LPRs) [5] and trap the light at the active layer [6], [7]. Since silver (Ag) NPs, in contrast to gold ones, typically can have a larger spectral overlap with absorption region of organic materials in the visible light region, and thus exhibit better improvements of short-circuit current (Jsc) and power conversion efficiency (PCE) [8]–[10]. Besides metallic nanoparticles (NPs), adopting periodic plasmonic structures is also an efficient approach to enhance optical absorption [11], [12]. The absorption efficiencies of OSCs embedded with the plasmonic NPs are comprehensively studied by using various numerical modeling techniques [13]–[17]. The near-field multiple scattering effects were investigated in [13] for both the active and
carrier transporting layers. Then the two-dimensional finite-element method (FEM) [2] was adopted to analyze light absorption in [14]. Moreover, metallic NPs with different geometries, such as spherical Ag nanoparticles and triangular Ag nanoprisms, are incorporated in OSCs to improve the power conversion efficiency (PCE) [15]. However, all the previous results and conclusions did not separate the contribution of plasmon resonance with other resonance mechanisms for boosting optical absorption of OSCs. The absorption enhancement comparisons between different geometries and materials have not been examined critically to unveil wave physics to achieve state-of-the-art light-trapping design based on NPs.

On the other hand, more efficient full-wave numerical solution to the optical response of high-performance photovoltaics are urgently required. A lot of three-dimensional numerical methods have been proposed to model the electromagnetic problems, such as scattering [18], [19], radiation [20], [21], electronic device modeling [22] and OSCs [14], [23]–[25], [27]. Because of huge computational resources and ill-conditioned matrix, it is tremendously challenging to design and optimize plasmonic OSCs by using the full-wave numerical methods. For the finite-difference frequency-domain (FDFD) [23] and finite-difference time-domain (FDTD) [26] methods, the rectangular meshes result in staircase errors, thus it is difficult to simulate the metallic NPs with high precision. More specifically, a lot of Lorentz-Drude terms are needed to fit the permittivity of dispersive materials for the time-domain methods, which leads to tremendous computing workload. Moreover, for the finite-element boundary-integral (FE-BI) method, the convergence is bad because of the ill-conditioned matrix. Finally, for the surface integral equation method [22], the fast algorithm is hard to be implemented. Therefore, the frequency-domain finite-element method (FEM) is more attractive than the above-mentioned numerical methods to model optical properties of OSCs.

In this work, the three-dimensional finite-element method is used to rigorously solve the Maxwell’s equations. All the simulations are taken by our own codes, which has been verified by other softwares. By using the tetrahedron meshes, metallic NPs with curved interfaces can be precisely modeled. Furthermore, the Floquet boundary condition is utilized to model the OSC device, where the distance between NPs are well separated to avoid degrading electrical properties of devices. In this way, only a unit cell needs to be calculated and the computational resources can be significantly saved. Additionally, the parallel technique is introduced to further accelerate the calculation. All the simulations are taken in visible light regime ranging from 400 to 800 nm. We theoretically investigate shape-dependent absorption of OSCs by appropriately manipulating the geometries of metallic NPs. To systematically examine the geometry-dependent plasmon resonance and meanwhile fairly compare the absorption enhancement between different NPs-embedded OSCs, four kinds of metallic shapes (nano-cone, nano-inverted-cone, nano-cylinder, and nano-cuboid) are modeled with the same volume (metal amounts). The work is critically important for designing and optimizing NPs-embedded thin-film solar cells.

The reminder of the paper is organized as follows: Section 2 presents the theory of the periodic finite-element method (p-FEM). Section 3 demonstrates the efficiency of the proposed method and study the dependence of light absorption on the shape of the NPs. Finally, a conclusion is presented in Section 4.

II. THEORY AND FORMULATION

In this section, the wave equation is formulated in terms of the scattered electric field, which can be written as

$$\nabla \times \nabla \times \mathbf{E}^s - \varepsilon_r k_0^2 \mathbf{E}^s = (\varepsilon_r - 1) \varepsilon_0 \omega^2 \mathbf{E}^i$$

(1)

where \(\mathbf{E}^s\) is the scattered electric field, \(\mathbf{E}^i\) is the incident electric field, and the position-dependent permittivity in inhomogeneous solar cell structure is \(\varepsilon_0 \varepsilon_r(r)\).

Then, as shown in Fig.1. The spacer layers is PEDOT:PSS and the active layer is P3HT:PCBM, Ag Nps is embed in the active layer, the top layer is TiO2 cathode and the bottom layer is metallic anode [30]. Meanwhile, the periodic boundary conditions are imposed to the OSC unit cell, and Sunlight is regarded as plane waves.

$$\begin{align*}
\mathbf{E}_R &= \mathbf{E}_L e^{-jmk_1 P} \\
\mathbf{E}_B &= \mathbf{E}_F e^{-jmk_3 P} \\
\mathbf{E}_C_3 &= \mathbf{E}_C_1 e^{-jP(mk_3 + nk_1)} \\
\mathbf{E}_C_4 &= \mathbf{E}_C_2 e^{-jP(mk_1 - nk_3)} \\
\mathbf{E}_R &= \mathbf{E}_L e^{-jnk_3 P} \\
\mathbf{E}_B &= \mathbf{E}_F e^{-jnk_1 P}
\end{align*}$$

(2)

![FIGURE 1. The schematic of the plasmonic OSC. (a) A schematic representation of the periodic OSC. The spacer layers is PEDOT:PSS and the active layer is P3HT:PCBM. The bandgap and density of states for the active layer are 1.1eV and 2.5 x 10^19 cm^-3 respectively. The green one is TiO2 cathode layer has an injection barrier of 0.2eV, the red one is metallic anode layer assumed to be an ohmic contact. The NPs are embedded in the active layer. (b) A single lattice of the OSC. The geometric size of the OSC cell is \(P \times P \times D_1\) for the PEDOT:PSS domain, \(P \times P \times D_2\) for the P3HT:PCBM domain. (c) Top view of the OSC cell. B, F, L, R represent the back, front, left and right sides of the OSC cell. C1, C2, C3, and C4 are the corners.](image-url)
where $k_x, k_y$ are the propagation constants of plane waves along the $x$ and $y$ directions, $m, n$ represent the number of the unit cells along the $x$ and $y$ directions.

### III. NUMERICAL RESULTS

The light absorption enhancement and Generation is defined as

$$EF = \frac{\int_{\lambda_{\text{PCBM}}}^{\lambda_{\text{Ag}}} |E_{\text{Ag}}(\lambda, r)|^2 dv}{\int_{\lambda_{\text{PCBM}}} |E(\lambda, r)|^2 dv}$$  \hspace{1cm} (4)$$

where $\lambda$ is the incident wavelength, $E_{\text{Ag}}$ represents the electric field at the active layer when the Ag NPs are embedded in active layer, $E$ donates the electric field at the active layer without Ag NPs, $h$ is the Planck constant, $n_c = n + ik_i$ is the complex refractive index of the active material, as shown in figure 2. And $\Gamma$ is the solar irradiance spectrum for AM 1.5G power of 100 $mW \cdot cm^{-2}$ to simulate the harvesting of sunlight at outdoor. It is worthy of noticing that the absorption of silver regions have been excluded and only active material absorption is taken into account. The common material of P3HT:PCBM is commercially available for active layer due to the complexity of the polymer chemistry, materials science, device engineering, and device physics involved [3].

At first, we consider the influence of NP materials on the absorption enhancement for the cubical geometry shape with $P = 80$ nm. The thickness of the active layer is $D_2 = 80$ nm and that of the spacer layer is $D_1 = 20$ nm. In this numerical example, three kinds of materials (Ag, Silicon, and perfect electric conductor) are used to comparatively study the absorption enhancement. The addition of Ag NPs into the active layer significantly enhances carrier mobility but decreases the total extracted carrier. The designed structure ensures the carrier collection efficiency by controlling the weight ratio for Ag NPs in the active layer [31]. The sizes of NPs is $P_A = D_3 = 27.15$ nm. As shown in Fig. 3, the absorption spectra of the OSC are demonstrated as a function of wavelengths for metallic NPs. It can be found that the
plasmonic enhancement are strongest due to the concentrated E-field around the metallic NPs. More specifically, the largest absorption enhancement factor can be obtained at the wavelength of 750 nm and it is up to 2. However, the absorption enhancement factor for PEC NPs as perfect reflectors is smaller than one since all the sunlight energy is reflected back from the metal surface to air. Similarly, for Si NPs, the absorption enhancement factor is near to one since its size is too small to allow for resonance (with small scattering cross section). Moreover, incorporating large dielectric NPs into very thin active layer (∼100 nm) is not practical for OSCs. Additionally, the material-dependent absorption profiles at the active layer are illustrated in Fig.3 with the wavelength of 400 nm, 650 nm, and 750 nm. At 400 nm, metallic NPs show weak plasmonic enhancement and large reflection can be observed as that in PEC material (perfect reflector) and silicon. As the wavelengths become longer and longer, plasmonic near-field enhancement around the Ag cubes, together with hot spots at the corners due to the lightning rod effect, can be clearly observed compared to other materials. Furthermore, we found that Ag NPs always achieve the best absorption enhancement (in contrast to other materials based NPs) no matter which geometries (cuboid, cylinder, cone, inverted-cone) are adopted. As shown in Fig. 4, the parallel efficiency is tested for 4, 8, 16 and 32 CPU cores respectively and it can be defined as follows.

\[ E_p = \frac{1}{N} \frac{S_1}{S_N} \]  

in which \( N \) is the number of cores, \( S_1 \) represents the simulation time for one core, \( S_N \) denotes the simulation time by using \( N \) cores. As the core number increases, the decreasing rate of parallel efficiency is noticeably reduced and the parallel efficiency tends to be stable, which suggests the FEM method developed is suitable for large-scale solar cell modeling.

Then the generation rates of the OSCs are theoretically simulated for nano-cone, nano-cylinder, nano-cuboid and nano-inverted-cone. It should be noted that the volume (metal amounts) of the Ag NPs remains unchanged for all the geometries. Firstly, for all the geometries, the excitons are dominantly generated from Sunlight illumination ranging from 400 nm to 650 nm, which is off plasmon resonance after comparing Fig. 5 (off plasmon resonances) to Fig. 6 (on plasmon resonances). For off-resonance cases at Fig. 5, the enhanced generation rates are gained by the height-dependent Fabry-Perot modes and there are the three peaks around 48 nm, 60 nm, 72 nm, which are identical for all NPs. Moreover, the largest generation rate can be obtained for nano-cone because of its tapered structure, which easily achieves impedance matching and reduced unwanted reflection. This argument could be reconfirmed by the worst absorption obtained by the nano-inverted-cone. It can be concluded that the capability of trapping light is enhanced significantly for this scheme. On the other hand, the localized surface plasmon mode is excited for the long wavelengths ranging from 650 nm to 800 nm as depicted in Fig. 6. The plasmon resonance has a bad spectral overlap with the absorption region of P3HT:PCBM. Because the strong active material absorption will damp the intensity of plasmon resonance [28]. As the height of Ag NPs increases, the geometric cross section of NPs (projection area at the xoy plane) decreases, which causes weak plasmonic absorption. The best generation rates is again achieved by nano-cone and it shows a broad-band enhancement from short to high altitudes. Consequently, it can be concluded that the Ag NP of nano-cone is the best concentrator from short wavelengths to long wavelengths. To further clarify the wave physics for the long-wavelength enhancement, the generation rate for a three-dimensional nano-cylinder (left y-axis) and the total scattering width for the corresponding two-dimensional nano-cylinder embedded in the P3HT:PCBM (right y-axis) are comparatively studied in terms of different radius. The total scattering width can be defined as

\[ \sigma(\lambda) = \frac{4}{k_0} \int_0^{2\pi} \left| \sum_{n \in \text{np}} a_n e^{in\varphi} \right|^2 d\varphi \]  

\[ a_n = \frac{\eta_1 J_n(k_0a)J_n(k_1a) - \eta_0 J_n(k_1a)J_n(k_0a)}{\eta_0 J_n(k_1a)H_n^{(2)\prime}(k_0a) - \eta_1 J_n(k_1a)H_n^{(2)\prime}(k_0a)} \] 

where \( a \) denote the radius of the 2D cylinder.

As shown in Fig. 7, two peaks correspond to the radius of 18.6 nm (height of 55 nm for the three dimensional nano-cylinder) and 17.1 nm (height of 65 nm for the three dimensional nano-cylinder). The peak positions of total scattering width of the 2D cylinder agree well with those of generation rate of the 3D cylinder, which suggests that plasmonic mode contributes to the improved absorption of OSCs at longer wavelengths. More interestingly, the enhancement peaks of nano-cone NPs have significant shifts compared to those of other NPs (See Fig. 6). Regarding the nano-cone NPs, the positions of enhancement peaks keep unchanged if one observes Figs. 6 and 7 together. These peaks are related to the vertical Fabry-Perot resonance of the nano-cone. Moreover, broadband plasmon resonances induced by the continuously changed cross sections make the peaks broaden. Thus, the hybrid Fabry-Perot-plasmon mode of the nano-cone
TABLE 1. Comparison of the maximum absorption enhancement factor for different geometries.

<table>
<thead>
<tr>
<th>Geometry</th>
<th>Maximum Absorption Enhancement Factor</th>
</tr>
</thead>
<tbody>
<tr>
<td>Nano-Cone</td>
<td>3.1</td>
</tr>
<tr>
<td>Nano-Cuboid</td>
<td>1.6</td>
</tr>
<tr>
<td>Nano-Cylinder</td>
<td>1.3</td>
</tr>
<tr>
<td>Nano-Inverted-Cone</td>
<td>0.9</td>
</tr>
<tr>
<td>Nano-Particles</td>
<td>1.2</td>
</tr>
<tr>
<td>Nano-prisms</td>
<td>1.2</td>
</tr>
<tr>
<td>Nano-Particles + Nano-prisms</td>
<td>1.3</td>
</tr>
</tbody>
</table>

FIGURE 5. Generation rates for different geometrical NPs. For all the geometries, the excitons are dominantly generated from sunlight illumination ranging from 400 nm to 650 nm, which is off plasmon resonance. The enhanced generation rates are gained by the height-dependent Fabry-Perot modes and there are three peaks around 48 nm, 60 nm, 72 nm, which are identical for all NPs.

NPs is responsible for the absorption enhancement at longer wavelengths.

To investigate the light trapping cases in details, the wavelength-dependent enhancement factors are illustrated in Figs. 8-10 for three different heights configurations. The absorption enhancement factor has a peak no matter what shape is embedded in the active layer. The shape of nano-cone performs best among them for all the heights at any
FIGURE 6. Generation rates for different geometrical NPs. For all the geometries, the excitons are dominantly generated from sunlight illumination ranging from 650 nm to 800 nm, which is on plasmon resonance. The localized surface plasmon mode is excited for the long wavelengths ranging from 650 nm to 800 nm.

TABLE 2. Comparison for different geometries.

<table>
<thead>
<tr>
<th>Geometries</th>
<th>Generation ($A/m^2$)</th>
<th>Absorption Enhancement Factor</th>
<th>Broadband properties</th>
<th>Manufacture process</th>
<th>Overall performance</th>
</tr>
</thead>
<tbody>
<tr>
<td>Nano-Inverted-Cone</td>
<td>9.8x10^{27}</td>
<td>3.1</td>
<td>Yes</td>
<td>Not easy</td>
<td>★★★★</td>
</tr>
<tr>
<td>Nano-Cone</td>
<td>8.7x10^{27}</td>
<td>1.2</td>
<td>No</td>
<td>Moderate</td>
<td>★★</td>
</tr>
<tr>
<td>Nano-Cuboid</td>
<td>9.2x10^{27}</td>
<td>1.6</td>
<td>No</td>
<td>Easy</td>
<td>★★★★</td>
</tr>
<tr>
<td>Nano-Cylinder</td>
<td>8.2x10^{27}</td>
<td>0.9</td>
<td>No</td>
<td>Not easy</td>
<td>★</td>
</tr>
</tbody>
</table>

wavelength. It can also be concluded that the distribution of the near-field at the wavelength of 660 nm is strongest (Figs. b-m of 8-10). The strongest near-field enhancement is always achieved by the plasmon mode at the resonating wavelength of about 660 nm. Despite the large metallic loss for the Ag NPs, the plasmon mode greatly boosts the near-field electric field resonating in the active layer. The best choice of height for NPs is 48 nm, which can gain the maximum absorption enhancement factor.

Comparisons of the maximum absorption enhancement factor for different geometries are made in Table 1. The maximum absorption enhancement factor of Nano-Cone
FIGURE 7. Generation rates for the nano-cylinder NPs (left y-axis) and total scattering width for the corresponding two-dimensional nano-cylinder embedded in the P3HT:PCBM (right y-axis). There are two peaks related to the radius of 18.6 nm (height of 55 nm) and 17.1 nm (height of 65 nm). The positions of peaks agree well with each other for these two case.

FIGURE 8. (a) Absorption enhancement for geometry-dependent NPs for the height of 48 nm. The absorption is calculated only from the P3HT:PCBM active material. Absorption profiles of active layer for different geometrical NPs: (b-e) 400 nm; (f-i) 660 nm; (j-m) 750 nm.

NPs is up to 3, which is superior to the other geometries. The performance for four kinds of NPs geometries are compared in Table 2. It can be concluded that the nano-cone performs best for generation, absorption enhancement factor
and broadband properties. In other words, it can significantly improve the utilization of solar radiation energy from short-wavelength to long-wavelength.

**IV. CONCLUSION**

A parallel finite-element method is presented to simulate thin-film plasmonic OSCs. Numerical examples show...
the material-dependent, cross-section-dependent height-dependent, and shape-dependent near-field light-trapping effects by various NPs. We found that Fabry-Perot mode induced enhancement is dominant from 400 nm to 650 nm and the plasmonic mode induced enhancement is dominated from 650 nm to 800 nm. All in all, the Ag NPs of nano-cone exhibit the highest optical absorption from short wavelengths to long wavelengths. It can be concluded from the numerical results that the highest absorption enhancement is dominant from 400 nm to 650 nm wavelengths to long wavelengths. It can be concluded from the numerical results that the highest absorption enhancement is dominant from 400 nm to 650 nm

### REFERENCES


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